8(0) SOV/112-59-1-986
Translation from: Referativnyy zhurnal. Elektrotekhnika, 1959, Nr 1, p 131 (USSR)
AUTHOR: Krest'yaninov, A. G., Vedyayev, Yu. M., and Nizhegorodtsev, N. N.
TITLE: Electrical Pickup for Short-Delay Blasting
PERIODICAL: Byul. tsvetn. metallurgii, 1957, Nr 11, pp 26-28
ABSTRACT: Delaying the action of an electric detonator can be achieved by a thyratron timer associated with a chargeable capacitor. The charging time can be adjusted within 0.01 - 0.07 Lec by 7 series-connected resistors. The pickup is AC supplied at 120 or 220 v, 70 w; its dimensions are 25x 35x 15 cm, weight 4 kg. The pickup circuit diagram is presented, as well as the method for, and results of its calibration and checking. The operating error found by tests is $\pm 10\%$ . In open-pit work, the blasted area was increased from 2.5 to 5 m, unsuitable-size pieces were cut to one-half, explosive consumption was reduced, and safety increased.
G.1.S.
Card 1/1











NIZHEGORODTSEV, V., inzh.

Technical aesthetics and the culture of production. Sov. profsoiuzy 17 no.15:28-30 Ag '61. (MIRA 14:7)

1. Gosudarstvennyy proyektno-tekhnologicheskiy i eksperimental'nyy institut "Orgstankinprom", rukovoditel' proyekta "Kul'tura mashinostroitel'nykh predpriyatiy".

(Industrial hygiene) (Labor productivity) (Color--Physiological effect)

APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R0011373







AN ACCOUNT OF A

NIZHEL'SKIY, P. Ye.

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- NIZHEL'SKIY, P. Ye.: "The content of gases in a liquid metal bath during the melting of the furnace charge in a basic open-hearth furnace". Sverdlovsk, 1955. Min Higher Education USSR. Ural Polytechnic Inst imeni S. M. Kirov (Dissertations for the degree of Candidate of Technical Science.)
- SO: Kniznnava Letopis! No. 50 10 December 1955. Moscow.

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HEL'SKIY, P.YE.	137-58-5-8870	
•	from: Referativnyy zhurnal, Metallurgiya, 1958, Nr 5, p 17 (USSR)	
AUTHOR	Nizhal'skiy, P. Ke	
TITLE:	The Influence of Carbon on the Solubility of Hydrogen in Iron Carbide Alloys (K voprosu o vliyanii ugleroda na rastvorimost vodoroda v zhelezouglerodistykh splavakh)	
PERIODIC	L: V sb.: Fizkhim, osnovy proiz-va stali. Moscow, AN 555R, 1957 pp 534-539. Diskuss. pp 650-655	
ABSTRACT Card 1/2	The investigation was performed in a vacuum device. Porce- lain and alundum crucibles were employed in the melting pro- cess. An ingot weighing 50-70 g and containing a specified amount of C ( $0.2-5\%$ ) was placed into a reaction tube which was then evacuated for 1.5 hrs. The evacuation continued until all of the metal had melted. At this point H <sub>2</sub> was introduced into the device in order to clean it out and to effect a reduction of the ferric oxides (three times). After another evacuation, during which the temperature of the melt was kept constant, H <sub>2</sub> was in- troduced once more in order to saturate the melt. The furnace was turned off 5-6 minutes after equilibrium was attained. Ex- periments were conducted under various pressures (20-500 mm	
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		137-58-5-8870
0 0 1 1 1 1 1	The Influence of Carbon (cont.)	
	Hg), the melt being maintained at a temperature of 1550 lished that the solubility of H decreases with increasing (particularly starting at 1.5% C). A tendency toward inc H was observed when the C content exceeded 4.3%. The dissolved increased with increasing C content. The shap curve of H in Fe-C alloys is similar in nature to the liqu	concentration of C reased solubility of rate at which H of the solubility
	system.	Ye.T.
	<pre>1. HydrogenSolubility 2. Iron alloysApplicationsSolvent action 4. CarbonApplications</pre>	3. Iron carbide alloys
	Card 2/2	
		Put of the second se

"APPROVED FOR RELEASE: Tuesday, August 01, 200 CIA-RDP86-00513R001137. UMERINE, P.V., doktor tekin.mauk prof.; KUBOCHKIN, K.E., kand.tekin.mauk, dots.; HIZEBL'SKIT, P.Te., kand.tekin.mauk Effect of early slag formation on hydrogen content in the metal during the open-hearth process. Trudy Ural.politekh. metal during the open-hearth process. (HIRA 13:4) inst. mo.75:7-19 '59. (Steel--Hydrogen content) (Open-hearth process) (Slag)

	S/276/63/000/002/012/052 A052/A126
AUTHORS :	Pan'shin, I.F., Bershteyn, L.I., and Nizhel'skiy, P.Ye.
	The second stage of austenite decomposition and properties of steel after refinement
	Referativnyy zhurnal, Tekhnologiya mashinostroyeniya, no. 2, 1963, 56, abstract 28240 (Izv. Kurganskogo mashinostroit. in-ta, I, 1962, 77-81)
1214) steel on tempering was heated during 920 and 950°S,	The dependence of toughness and hardness of $30X2H2M$ ( $30Kh2$ - the hardening temp. ature and on temperature and duration of investigated. For hardening, 10 x 10 x 55 mm samples were 15 min in an electric furnace having temperatures of 890, and they were cooled in calm air. By the magnetometric been established that austenite decomposition begins at

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Card 2/2		
A L 13072-66 EWT (m)	/EWA(d)/T/EWP(t)/EWP(z)/EWP(b)/EW/	
ACC NR: AP6001688	SOURCE CODZ: UR/0148/6	65/000/012/0116/012159
AUTHOR: Nizhel'skiy, P. Ye.;	; Pan'shin, I. F.	58
ORG: Kurgan Machine Building	Institute (Kurganskiy mashinostr	coltel'nyy institut) B
	d structural state of chromium ma	
	lurgiya, no. 12, 1965, 116-121	Process Process
TOPTC WARE		
TOPIC TAGS: metal scaling, c strinkess steel, heat resistan	rystal structure, chromium steel, in teel ortage of nickel, an increasing si	

plem 18 how to determine the optimal ratio between Mn and Cr so as to optimally combine scaling resistance with high-temperature strength in the steels used as the material of furnace figtings. In this connection, the authors investigated the scaling resistance of E1921 Cr-Mn steel (0.6% C, 17% Cr and 0.5% Si) and other steels as a function of Mn content and the ambient medium. Scaling resistance was determined by Card 1/2 IICC-669.15-194:669.26174 13072-66 ACC NRI AP6001688 heating annealed and degreased specimens in muffle furnaces at 700, 850 and 1000°C for 2, 4, 8, 24, 48, 86, and 100 hr, and, after cooling, weighing them in order to determine from their weight gain the oxidation rate as a function of heating time. Corrosion resistance was determined by heating the specimens for 100 hr at 1000°C in a  $SO_2$ atmosphere. The structural state of the specimens was estimated by magnetometric measurements, metallographic analysis, and measurements of hardness and microhardness: the steels containing 0-13% Mn have a mixed structure consisting of  $\alpha$ - and  $\gamma$ -solid solutions. Above 13% Mn, the structure is represented by the y-solid solution alons. It is at this transition point from  $\alpha$ - to  $\gamma$ -solid solution that the gas corrosion is the smallest, which is why a 13% Mn content may be considered optimal. Thus, the scaling resistance of medium-carbon Cr-Mn steels is determined not only by their chemical composition but also by their structural state. In this connection, it is worth noting that the 13% Mn content of EI921 type steel is highly cuitable. Orig. art. has: 2 tables and 6 figures. SUEM DATE: 15Ju164/ ORIG REF: 007/ OTH REF: 000 SUB CODE: 11/ APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R0D11 Card 2/2

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Translation f AUTHORS: TITLE:	SO rom: Referativnyy zhurnal. Metallurgiya, 1959, Nr Ipat'yev, V.V., Nizhel'skiy, V.F., Vladimirova, M. Atmospheric Oxidation of Cobalt and Alloy of Iron Wi (Okisleniye v vozdukhe kobal'ta i splava zheleza s 13°	G . th 13% Cobalt
PERIODICAI	: Tr. Leningr. lesotekhn. akad. 1958, Nr 80, part	2, pp 47-56
ABSTRACT:	The authors investigated the kinetics of atmospheric in the 700-1200°C temperature range and of an alloy Co (I) in the 600-1100° range by the method of period specimens without removing them from the furnace r It was found that the oxidation of Co and I is subject to law. Micrographic investigations revealed that at 90 1200° Co scale consists of CoO with small inclusions grains of secondary origin. The I scale at 1000° con three following layers: $R_2O_3$ , $R_3O_4$ , and $RO_5$ .	lic weighing of reaction tube. to a parabolic 00, 1000, and s of Co3O4
Card 1/1		
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s/137/62/000/002/102/14 A060/A101

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(1) 12 (1) 22 (1) 23 (1

Vladimirova, M. G., Nizhel'skiy, V. F. AUCHOPS: Oxidation of molybdenum and its alloys with iron in an air environment

TITLE: Referativnyy zhurnal, Metallurgiya, no. 2, 1962, 81, abstract 21550 ("Nauchn, tr; Leningr, lesotekhn, akad.", 1961, no. 92, pt. 3, PERIODICAL: 105 - 115)

The oxidation of Mo in the temperature range 350 - 550°C proceeds basically according to the parabolic law. Oxides forming on the Mo in the course of oxidation in air consist of MoO2 and MoO3. The process of oxidation of Fe-Mo alloys containing 5 and 10% Mo occurs according to the parabolic law and the temperature dependences of the processes may be expressed by the equations

log K = - 39,685/4.57 T + 7,64 (for the 5% alloy)

and

log K = - 40,535/4.57 T + 8.04 (for the 10% alloy)

The scale on Fe-Mo alloys with 5 and 10% Mo under oxidation in air (700 -  $900^{\circ}$ C)

Card 1/2

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CIA-RDP86-00513R0011373

S/137/62/000/CC2/101/14 A060/A101 AUTHORS: Nizhel'skiy, V. F., Vladimirova, M. O. TITLE: On the problem of oxidation of cobalt in air PERIODICAL: Referativnyy zhurnal, Metallurgiya, no. 2, 1962, 81, abstract 21548 ("Nauchn. tr. Leningr. lesotekhn. akad.", 1961, no. 92, pt. 3, 117-119) TEXT: In the course of oxidation of Co covered with metallic Au, the layer of Co oxide which forms in air at 800 - 950°C grows on account of Co diffusion (by 72%) and on account of O<sub>2</sub> diffusion (28%). Authors' summary [Abstracter's note: Complete translation]

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ACC NRI A	P6030895	SOUR	CE CODE: UR/O	080/66/039/008/1689/	1693
AUTHOR: NI	zhel'skiy, V. F.;	Vladimirova, M. G	<u>•</u>	4	11
ORG: Lenin	grad Forestry Eng	incering Academy in	m. S. M. Kirov		3
lesotekhnic	heskaya akademiya		n 11		
TITLE: Oxi	dation of cobalt	in sulfur dioxide	and <u>carbon</u> diox	ide gas at <u>high</u>	
temperature	18 1				
SOURCE : Zh	urnal prikladnoy	khimii, v. 39, no.	8, 1966, 1689	-1693	
gas corrosi	ion, high temperat	ure oxidation		rbon dioxide corrosi	
	Specimens of 99.9	-pure electrolyti	c cobalt were	tested for oxidation	n ate in
ABSTRACT:		and corpon 010110	16 MF 000-TTOA	C. Inc Oktable -	
resistance	in sulfur dioxide	he nareholic and a	ubstantielly ni	Phot when the second	1
resistance sulfur dio:	in sulfur dioxide	be parabolic and a	ubstantially ni		
resistance sulfur dio: of in carbo 760-950C	in sulfur dioxide cide was found to on dioxide (see Fi consists of coba	be parabolic and a g. 1). The oxide t oxides and sulfi	layer formed i des (Co <sub>4</sub> S <sub>3</sub> ).	The layer formed at The sulfur content	in ·
resistance sulfur dio: of in carbo 760-950C	in sulfur dioxide cide was found to on dioxide (see Fi consists of coba	be parabolic and a g. 1). The oxide t oxides and sulfi	layer formed i des (Co <sub>4</sub> S <sub>3</sub> ).	The layer formed at The sulfur content	in ·
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resistance sulfur dio: of in carbo 760-950C	in sulfur dioxide cide was found to on dioxide (see Fi consists of coba	be parabolic and a g. 1). The oxide t oxides and sulfi	layer formed i des (Co <sub>4</sub> S <sub>3</sub> ).	The layer formed at The sulfur content	in ·





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	504/24-38-7-31/30
6	Meremenko, V.N., Ivashchenko, Yu.N., Nizhenko, V.I. and Fesenko, V.V. (Kiyev) Determination of the Surface Tension of Metals of the
	Iron Family (Opredelenitye poverminester)
PERIODICAL:	Izvestiya Akademii nauk SSSR, Otdeleniye tekhnicheskikh nauk, 1958, Nr 7, pp 144 - 146 (USSR)
	nauk, 1998, MP 7, pp 11. The authors point out that wide discrepancies ëxist in the published data on the surface tension of iron (Refs 1, 2) and nickel (Refs 3-5) and that only one investigation has been made on that of cobalt (Ref 5), investigation has been made on that of cobalt (Ref 5), They describe an investigation in which the surface tension of these metals (less than 0.01% impurity) was measured by two methods. In experiments by the recumbent drop method the drop was supported on pure alumina, beryllia or magnesia in a water-cooled quartz tube with suitable screening. Heating was by induction with a graphite element, temperature measurement by a previously calibrated optical pyrometer to an accuracy of 20 °C. The apparatus, shown in Figure 1, was provided with an
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	an a

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Determination of the Surface Tension of Metals of the Iron Family

optical system for photographing the shadow of the drop. Tests were carried out in vacuo and also in purified helium and hydrogen. The surface tension was ælculated with the use of published tables (Ref 6). The reliability of the method was checked by determining the surface tension of aluminium and good agreement with published data was obtained. A second series of determinations was made with the bubble-pressure method (Figure 2). A beryllium capillary was used, allowance being made for wall thickness. Metal temperatures were measured to # 10 °C with a type TsNIIChM-1 tungsten-molybdenum thermocouple. Purified helium and hydrogen were used to form the bubble. The results obtained by the two methods at 1 470 - 1 650 °C are tabulated, showing that the accuracy of both is about # 5%. There are 2 figures, 1 table and 12 references, 3 of which are Soviet, 6 English and 3 German.

Card 2/3

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 "APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137.
SOV/24-58-7-31/36
Determination of the Surface Tension of Metals of the Iron Family
ASSOCIATION: Institut metallokeramiki i spetsial'nykh splavov AN USSR (Cermets and Special Alloys Institute, Ac.Sc., Ukrainian SSR)
SUEMITTED: October 17, 1957

Card 3/3



APPROVED FOR RELEASE: Tuesday, August 01, 2000

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CIA-RDP86-00513R001137 "APPROVED FOR RELEASE: Tuesday, August 01, 2000

**S/081/61/000/024/014/086** B138/B102 Yeremenko, V. N., Nizhenko, V. I., Ivashenko, Yu. N. AUTHORS: Stationary drop method of measuring the surface tension of TITLE ; metals of the iron group Referativnyy zhurnal. Khimiya, no. 24, 1961, 94, abstract PERIODICAL: 24B690 (Byul. In-t metallokeram. i spets. splavov, AN USSR, no. 4, 1959, 65 - 71) TEXT: An apparatus has been designed for the measurement of surface tension o of molten metals, both in a vacuum and in protective atmospheres. using the stationary drop method and h-f heating up to 1750°C. o was determined for aluminum in a vacuum and in a helium atmosphere. The results are in agreement with published data. Within the limitations of experimental error, estimated at 2 5%, the h-f field did not influence the  $\sigma$  value of molten metals under the conditions used in this case.  $\sigma$  was measured for metals of the iron group. [Abstracter's note: Complete translatio 1 Card 1/1

	80987	
TITLE	S/180/60/000/03/021/030 E193/E283 Surface Tension of Liquid Beryllium $V$ Izvestiya Akademii nauk SSSR, Otdeleniye tekhnicheskikh nauk, Metallurgiya i toplivo, 1960, Nr 3, p 116 (USSR) Large grain size and the columnar structure of cast beryllium cause difficulties in machining of this metal. Since addition of surface-active substances is one of the methods used in grain refining, determination of the surface properties of beryllium and its alloys is of the surface protective importance. Taylor (Ref 2),	
Card1/3	using a semi-empirical formula, calculated to be using a semi-empirical formula, calculated to be tension of beryllium at its metting point to be $1620 \text{ erg/cm}^2$ . The object of the investigation described in the present paper was to determine surface tension of beryllium experimentally, using the sessile drop method. The measurements were made at 1 500 °C on refined The measurements were made at 1 500 °C on refined beryllium, 99.98% purity, melted in vacuum (5 x 10 <sup>-5</sup> mm Hg) beryllia crucibles. The density of beryllium at in beryllia crucibles. The density of beryllium at 1 500 °C was determined from the dimensions of the drop, photographed at that temperature and from the weight of	

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		83666	
18 6100 ml	12308	S/073/60/026/004/008 B016/B054	
AUTHORS:	Yeremenko, V. N. and	Nizhenko, V. I.	
TITLE:	The Influence of Car A Cobalt and NickelyAs With Aluminum Oxide	bon <sup>2</sup> on the Surface Tension of Liquid Well As Their Interface Tension	
PERIODICAL:	Ukrainskiy khimichesk pp. 423-428	tiy zhurnal, 1960, Vol. 26, No. 4,	
on the surfa this tension temperatures heating by m for this pur vacuum was p a forepump o data for the	ce tension of liquid c in liquid metals and (1550-1600°C) in vacuu uch improved apparatus pose. Figs. 1 and 2 sh produced by a vacuum pu of the type PBH-20 (RU surface tension with	blications on the influence of carbon cobalt and nickel, the authors measured alloys and the wetting angles at high to or in protective gas. Inductive (as compared with Ref. 1) was used now this apparatus schematically. The imp of the type $\underline{NBA} - 100 (\text{TsVL} - 100)$ and $\underline{NN-20}$ Table 1 compares the authors' data in publications (Refe. 4-6). of the surface tension in Ni-C alloys	

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Liquid Cobalt and Michael Monade		
linearly with the concentration when From a comparison of the influence of nickel and cobalt, the authors concl more surface-active than in liquid of the adhesion energy w and the tensi	The curve of Fig. 4 was obtained by introduction of the values of $\frac{\partial \delta}{\partial C}$ deal systems. The isothermal line of s shown in Fig. 5. Adsorption increases in the concentration range investigated f carbon on the surface tension of ude that carbon in liquid nickel is obalt. Finally, the authors calculated on $\delta$ at the interface	
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**s/073/60/026/005/00**9/019 18.7200 B004/B063 AUTHORS: Yeremenko, V. N. and Nizhenko, V. I. TITLES Wettability of Aluminum Oxide by Means of Liquid Tin-Titanium Alloys and Their Interfacial Stress on the Boundary With Aluminum Oride PERIODICAL: Ukrainskiy khimicheskiy zhurnal, 1960, Vol. 26, No. 5. pp. 605-608 TEXT: In a previous work (Ref. 2), the authors had found that an admixture of 0.083 % by weight of Ti lowers the surface tension of tin at 300°C from 539 ergs/cm<sup>2</sup> to 155 ergs/cm<sup>2</sup>. An Sn-Ti alloy containing 0.2% of Ti has a wetting angle that is much smaller than 90°. This may be of practical importance when soldering ceramics with ceramics or metals. From this point of view the authors have studied the effect of adding Ti to Sn on the stress on the interface between the Sn alloy and solid oxide  $(Al_20_5)$ . Using the data of Ref. 2 on the surface tension  $\mathcal{O}_{liq}$  of Sn-Ti alloys, the Card 1/

86157 s/073/60/026/005/009/019 Wettability of Aluminum Oxide by Means of B004/B063 Liquid Tin-Titanium Alloys and Their Interfacial Stress on the Boundary With Aluminum Oxide wetting angle  $\theta$  , and the surface tension  $\sigma_{gd}$  of solid  $\texttt{Al}_20_3$  which was set equal to 1050 ergs/cm<sup>2</sup> according to Ref. 4, the interfacial stress was calculated from the relation  $\sigma_{int} = \sigma_{sd} - \sigma_{liq} \cos \theta$  (1). At 300°C, the following values were obtained for an increase in Ti concentration C: Gint, erg/cm<sup>2</sup> C, g-atom/1.10<sup>4</sup> G<sub>lig</sub>, erg/cm<sup>2</sup> 9, degree 1465 140 539 0.00 1300 149 292 12.86 1190 148 155 48.53 This effect was ascribed to a reaction with oxygen. Though the concentration of  $O_2$  at 10<sup>-4</sup> mm Hg does not affect the surface tension of Sn, the Ti admixture acts as a getter and adsorbs oxygen which, in turn, lowers the surface tension. The iridescence observed is also indicative of a reaction with oxygen. Experiments with a Ni-Ti alloy in hydrogen have shown that Card 2/4

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CIA-RDP86-00513R001137

YEREMENKO, V.N. (Kiyev); MIZHENKO, V.I. (Kiyev); NAIDICH, Yu.V. (Kiyev) Surface tension of certiin molten intermetallides. Izv. AN. §SSR. Otd. tekh. nauk. Met. i topl. no.3:150-154 My-Je '61. (MIRA 14:7) 1. Institut metallokeramiki i spetsial'nykh splavov AN USSR. (Surface tension) (Intermetallic componds)

"APPROVED FOR RELEASE: Tuesday, August 01, 2000

21,655

S/076/61/035/006/007/013 B127/B203

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AUTHORS: Yeremenko, V. N. and Nizhenko, V. I.

TITLE: Effect of titanium admixtures on the surface tension of nickel and cobalt and on their interfacial tension with aluminum oxide

PERIODICAL: Zhurnal fizicheskoy khimii, v. 35, no. 6, 1961, 1301-1306

TEXT: The present paper deals with the effect of titanium admixtures on the surface tension of Ni and Co, which metals are used in powder metallurgy as binding agents for titanium carbide, titanium nitride, or titanium boride. The surface tension is determined by the method of the drop lying on a horizontal base. For the alloys, 99.99 % pure Ni and Co, as well as titanium iodide with less than 0.07 % impurities, were fused together in the arc furnace. The tables of Bashforth and Adams in a modified form were used to calculate the surface tension. Besides, a new table was compiled with the values  $\Phi$  in direct dependence on x/z of the drop (Fig. 1) at  $\varphi = 60^{\circ}$ . The function, was  $\Phi = b^2/\beta(2x)^2$ . The surface tension  $\sigma$  was calculated from  $\sigma = \Phi(2x)\Delta qg$ . The error of measurement was

Card 1/

APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R0011373

"APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137 21,655 s/076/61/0;5/006/007/013 B127/B203 Effect of titanium admixtures on... 3-5 %. In the system Co, To, Al<sub>2</sub>O<sub>3</sub>, the study was conducted in vacuum at 1.10<sup>-4</sup> mm Hg and 1600°C. The titenium content was 1.96 %. Titanium admixtures of 0.23 g-atom/1 and more showed no effect on the surface tension. With 0.05 g-atom/1 Ti, the interfacial tension at the boundary  $Co = Al_2O_3$  dropped by more than 1000 erg/cm<sup>2</sup>. The adhesive power increased simultaneously with the reduction of interfacial tension. Thus, a considerable interaction between alloy and Al203 base took place. In the system Ni, Ti, and Al<sub>2</sub>0<sub>3</sub>, the same results were obtained as for Co. At a vacuum of  $1 \cdot 10^{-4}$  mm Hg, the specimen was always covered with a thin, but noticeable oxide layer during the experiment. The same phenomenon appeared in the case of BeO instead of Al<sub>2</sub>O<sub>3</sub> as a base; likewise, in higher vacuum obtained by freezing the vapors of the oil diffusion pump with liquid N<sub>2</sub>. On addition of Ti, a reduction of the Ni surface tension All this changed abruptly if the experiments were made in In this case, no activation by Ti on the interface Ni - gas was observed. H<sub>2</sub> atmosphere. The interfacial activity increased at the same time. The was observed. Card 2/6
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s/076/61/ B127/B203

Effect of titanium admixtures on ...

same occurred by melting the specimen in  $H_2$  medium, and subsequent separation of  $H_2$  by evacuation. In the system Sn, Ti,  $Al_2O_3$ , a high surface activity of titanium was observed at the interface of the liquid Sn. This effect is explained by the adsorption of  $O_2$  residues from the vacuum by:Ti.  $O_2$  causes the surface activity. Adsorption of Ti at the metal  $-Al_2O_3$ interface. In the Ni and Co system, Ti develops higher interfacial activity due to high formation energy of the lowest Ti oxide. With the use of the Gibbs adsorption equation, the excessive Ti concentration at the interface metal  $-Al_2O_3$  was calculated (by graphical differentiation of the curve). Fig. 4 shows the results for Co - Ti and Ni - Ti on  $Al_2O_5$ . In the maximum of the curve, the corresponding thickness of the adsorption layer is  $2.7 \cdot 10^{-8}$  cm. It is assumed that the lattice nodes occupied by O ions are the active centers of adsorption of Ti atoms on the  $Al_2O_3$ swrface. In maximum adsorption, every Ti is bound to an O. The authors mention joint papers by V. N. Yeremenko with Yu. V. Naydich and

Card 3/6

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Effect of titanium admixtures on	S/076/61/035/006/007/013 B127/B203	
A. A. Nosonovich: Elektronika, no. 4, 1 1186, 1960. There are 4 figures, 2 tabl bloc and 3 non-Soviet-bloc. The most re language publication reads as follows: Soc. 37, 42, 1954.	Les, and 11 references: 8 Soviet- ecent reference to the English-	7
ASSOCIATION: Institut metallokeramiki i of Powder Metallurgy and S		
SUBMITTED: September 25, 1959		
Fig. 1: Diagram for calculating the surface tension from the form of the drop.	rege	
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"APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137 5/075/62/028/004/004/004 1017/1217 Yeremenko, V.N., Nizhenko, V.I., Levi, N.I., and AUTHORS : Bogatyrenko, B.B.-Surface tension of liquid alloys of binary metalic sys-TITLE: tems having maximum on the liquidus curve Ukrainskiy khimicheskiy zhurnal, v.28, no.4, 1962, PERIODICAL: 500-505 TEXT: The surface tension and the density of liquid alloys of nickcl with aluminum at E40°C and nickel with berilium at 1500°C were determined. It was found that the formation of the alloys in the studied systems, is accompanied by chemical interaction which causes decreasing of volume and negative deviation of the isotherm of the spacific volumes from the additive values. The analogy between the type of diagrams ; surface tension/composit-ion and the diagram of state is stated. The compound NiBe is inactive toward bothe the components of the system. The compound NIAI Card 1/2 П

APPROVED FOR RELEASE: Tuesday, August 01, 2000

CIA-RDP86-00513R0011373

47/030795	\$/0000/63/000/000/0097/0109
ACCESSION NR: AT4030795 AUTHOR: Yeremenko, V. N.; Nishenko,	Ver Iennens
Surface properties of nickel	based alloys
SOURCE: AN UKrSSR. Institut metallo Poverkhnostnytye yavlailys v resplay	okeramiki i spetsisl'nymkh spisvov. okh i protsessakh poroshkovoy metallurgii (sur- processes in powder metallurgy). Kiev,
TOPIC TAGS: surface property, nicke surface, nickel, aluminum oxide, sur	l based alloy, powder metallurgy, infusible face tension, binary alloy, copper containing
alloy ABSTRAGT: The results of the invest for the same systems. The authors of for alloys in a system with inorgan state, was given by Zhukhovitskiy's 1944, p. 214) for an ideal solution	igation were compared with disgrams of conditions oncluded that the isotherm of surface tension ic solubility in the solid, as well as the liquid equation (A. A. Zhukhovitskiy, ZhFKh, vol. 18, (nickel-copper). In the binary liquid systems ast surface tension had an active surface rela-
tive to the second composition practically ceased in a composition Card 1/2	lowering of the surface tension in the former which corresponded to the monotectic point

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coordinate (nickel-silver). and the isotherm of the surfa face tension in alloys from with maxima on the fusibility electron compounds having an form of a maximum (nickel-best tected on the isotherms of su were not detected although the electron compound Ni <sub>3</sub> Sn havin path. Orig. art. has: 12 fe		viation of the sur- ished that in systems cuently melting reme points in the -aluminum) were de- system, such points imposition of the 5 had an abnormal	
ASSOCIATION: Institut metal of Powder Metallurgy and Spec	lokeramiki i spetsial'ny%kh splavov Mal'Alloys, AN UkrSSR)	r AN J <b>ITSSR(In</b> stitute	
SUBMITTED: 23Nov63	DATE ACQ: 16Apr64	ENCL: 00	
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YEREMENKO, V.N.; NIZHENKO, V.I.

STREET ALL CONTRACTOR

Surface properties of nickel-based liquid alloys. Part 1. Effect of silver on the surface tension of nickel. Ukr. khim. shur. 29 no.11:1157-1160 '63. (MIRA 16:12)

1. Institut metallokeramiki 1 spetsial'nykh splavov AN UkrSSR.

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TTLE: On the Surface active additions in liquid matals NORCE: Foroshkovaya matallurgiya, no. 2, 1964, 11-18 NOPIC TAGS: liquid metal, addition, surface activity, sublimation, malting tem- merature ABSTRACT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and colvent, as well as the differences of full potential barriers, are proposed as new criteria. They graphically present relationships between the specific heat of sub- limation and the malting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- cential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteris of surface activity in the matal systems are presented in a trible. This reliability was checked by experimental data of over 100 metal	AUTHOR: <u>Mishenko, V. I.</u> : Yeremenko, V. N. TITLE: On the surface active additions in liquid matals SOURCE: Poroshkoways metallurgiys, no. 2, 1964, 11-18 TOPIC TAGS: liquid metal, addition, surface activity, sublimation, melting tem- perature AESTRACT: In this paper the authors discussed the criteris of surface activity. The differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new criteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sub- limation and the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- tential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteris of surface activity in the metal systems are presented in a table. This reliability was checked by experimental dats of over 100 metal systems. The best criteria proved to be the difference between the free surface	CCESSION MR: AP4029201	\$/0226/66/000/002/0011/0018	
SOURCE: Poroshkovaya matallurgiya, no. 2, 1964, 11-18 SOPIC TAGS: liquid metal, addition, surface activity, sublimation, melting tem- merature SESTRACT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new criteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- cential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteria of surface activity in the matal systems are presented in a total. This year and for the metal of a surface activity in the matal systems are presented and the hardness are presented by experimental data of over 100 metal	SOURCE: Foroshkovaya matallurgiya, no. 2, 1964, 11-18 FOPIC TAGS: liquid metal, addition, surface activity, sublimation, melting tem- perature ABSTRACT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new criteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- tential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteria of surface activity in the matal systems are presented in a table. This reliability was checked by experimental data of over 100 metal systems. The best criteria proved to be the difference between the free surface	UTHOR: Mishenko, V. I.; Yeremenko, V. K.	•	
OPIC TAGS: liquid metal, addition, surface activity, sublimation, melting tem- erature BSTRACT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new insteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- contial barrier and hardness. Properties of the elements used for evaluating the reliability of the criteris of surface activity in the matal systems are presented in the surface reliability was checked by experimental data of over 100 metal	OPIG TAGS: liquid metal, addition, surface activity, sublimation, melting tem- berature BESTRAGT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new writeria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface intergy, the total potential barrier and the melting temperature, and the total po- cential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteris of surface activity in the matal systems are presented in a table. This reliability was checked by experimental data of over 100 metal systems. The best criteria proved to be the difference between the free surface	ITLE: On the surface active additions in lig	pid matals	
BESTRACT: In this paper the authors discussed the criteria of surface activity. BESTRACT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and colvent, as well as the differences of full potential barriers, are proposed as new criteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- contial barrier and hardness. Properties of the elements used for evaluating the reliability of the criteris of surface activity in the matal systems are presented in a total potential barrier and the metal systems are presented	BESTRAGT: In this paper the authors discussed the criteria of surface activity. The differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new writeria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the matting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface mergy, the total potential barrier and the melting temperature, and the total po- cential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteria of surface activity in the matal systems are presented in a table. This reliability was checked by experimental data of over 100 metal systems. The best criteria proved to be the difference between the free surface	OURCE: Foroshkoveys matallurgiys, no. 2, 196	i4 <b>, 11-18</b>	
the differences in the specific heats of sublimation of the dissolved substance and colvent, as well as the differences of full potential barriers, are proposed as new eriteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the melting temperature of the metals, the specific heat of sublimation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- cential barrier and hardness. Properties of the elements used for evaluating the reliability of the criteria of surface activity in the matal systems are presented in a table. This reliability was checked by experimental data of over 100 metal	the differences in the specific heats of sublimation of the dissolved substance and solvent, as well as the differences of full potential barriers, are proposed as new eriteria. They graphically present relationships between the specific heat of sub- limation and the melting temperature of the metals, the specific heat of sublimation and the hardness of the metals, the total potential barrier and the free surface energy, the total potential barrier and the melting temperature, and the total po- contial barrier and hardness. Properties of the elements used for evaluating the reliability of the criteria of surface activity in the matal systems are presented in a table. This reliability was checked by experimental data of over 100 metal systems. The best criteria proved to be the difference between the free surface		activity, sublimation, melting ten-	
	ard 1/2	he differences in the specific heats of subli- olvent, as well as the differences of full po- riteria. They graphically present relationsh imation and the melting temperature of the me and the hardness of the metals, the total poto- mergy, the total potential barrier and the me contial barrier and hardness. Properties of eliability of the criteria of surface activity and table. This reliability was checked by	imation of the dissolved substance and otential barriers, are proposed as new hips between the specific heat of sub- etals, the specific heat of sublimation ential barrier and the free surface elting temperature, and the total po- the elements used for evaluating the ty in the matal systems are presented experimental data of over 100 metal	

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ACCESSION NR: AP4021975 AUTHOR: Yeremenko, V. N.; Nishenko, V. TITLE: Surface properties of liquid al		
SOURCE: Ukrainskiy khimicheskiy zhurnal TOPIC TAGS: liquid nickel alloy, nickel property, surface tension, density, den	L, v. 30, no. 2, 1964, 125-132 L tin alloy, metalloceramics, surface	
additive, Ni <sub>5</sub> Su, Ni <sub>5</sub> Su <sub>2</sub> , capillary pro system, wetting ability, refractory wet ABSTRACT: Surface properties are very	perty, refractory, nickel tin alumina	
Liquid alloys based on nickel at the in interface in contact with the surfaces of its dependence on temperature of liquid	erefore made of the surface properties of terface with the gas phase and with the of refractory materials The density and alloys of the Ni-Sn system were determine lloys at 30 and 1500 C showed a significan	d
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NATE AN A HARMADE AND A DESCRIPTION AND A ACCESSION NR: AP4021975 deviation from additive values. The density-temperature relationship of liquid Ni is approximated by the equation:  $e = 7.78 - 0.0006(t-1453) \text{ gm/cm}^3$ . The surface tension of Ni was determined in the 1500-1790 C temperature interval; the surface tension-temperature relationship is described by the equation: c = 1.745 - 0.34(4-1500) erg/cm<sup>2</sup>. For Sn the surface tension-temperature function is described by  $\epsilon = 510 = 0.092(t-800)$  erg/cm<sup>2</sup>. The surface tension at 1500 C of various alloys (including Ni, Sn and Ni, Sn 2) of the Ni-Sn system was also determined. The deviation of the surface tension-concentration isotherm from the isotherm for an ideal solution is explained by the retention, in the liquid state, of groups of atoms corresponding to the intermetallide Ni.Su. The effect of the addition of up to 1.0% Sn ou the surface tension of Mi, and on its interphase tension at the interface with ALO, was investigated; on in small amounts is a surface active additive. The wetting of Al\_0, with liquid Ni-Sn alloys was determined by measuring the angle of contact on Al\_Og. The capillary properties of these Mi-Sn alloys was determined 2/3

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Ni-Sn alloys at 15 bas: 7 figures, 1	00 C at the inte table and 5 equa	rface with Al <sub>2</sub> 0 <sub>5</sub> were tions.	calculated. Orig.	art.
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ACC NRI	AR6035409	SOURCE COD	S: UR/0137/66/000/009/A	8004\800	
AUTHOR:	Nizhenko, V. I.; Yeren	ænko, V. I.; Sklyarenk	0, L. I.		
TITLE: liquids	Use of the lying drop m that wet the substrate	ethod to determine the material	surface energy and dens	sity of	
SOURCE:	Ref. zh. Metallurgiya,	, Abs. 9A51			
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TOPIC TR	ACS: surface property, Alcium fluoride, copper	liquid property, surfa	ice energy, fluid density	r measure-	
tion of drop of	the surface energy and the wetting liquid on a ves verified on Car end as. 4 illustrations. 1	density of liquids by a substrate even at con Cu. The data obtain	t be used for an exact de forced formation of a s ntact angles less than 4 ed agree with the earlies a. (From RZH Fiz.) [Tr	5°. The r deter-	
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ACC NRI ARGO35408	SOURCE CODE: UR/0137/66/000/009/A007/A007
AUTHOR: Yeremenko, V. N.; Nizhenko,	V. I.; Sklyarenko, L. I.
TITLE: Surface properties of chrome	e-nickel alloys
SOURCE: Ref. za. Metallurgiya, Abs.	. 9844
REF. SOURCE: Sb. Poverkhnost. yavle tverd. fazakh. Nal'chik, 1965, 297-3	eniya v rasplavskh i voznikayushchikh iz nikh 301
TOPIC TAGS: surface property, surfa molten metal	ace tension, wichrome alloy, temperature dependence
by the large-drop method in a helium concentration. The chromium reduces content exceeds 10 at.%. A minimum near 50 at.% Cr. A study was made of tact angle when Al <sub>2</sub> O <sub>3</sub> is wetted by m teristics in the CF-Mi melt + Al <sub>2</sub> O <sub>3</sub> 30 at.% chromium; with further incre	d the density of nichrome alloys were investigated a atmosphere as a function of the temperature and s the $\sigma$ of liquid Ni, especially when the chromium is observed on the isotherm of $\sigma$ at concentrations of the temperature and time dependence of the con- nolten nickel or Cr-Ni. The best adhesion charac- system is possessed by nichromes containing up to ease of the chromium content, the temperature at imal increases. Therefore nichromes containing up
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L 34084-66 EAT(m)/T/EWP(t)/ETI IJP(c) JD/WH/JW/HW/JG ACC NR: AP6025520 AUTHOR: Teremenko, V. N. (Kiev); Nizhenko, V. I. (Kiev); Sklyarenko, L. I. (Kiev) AUTHOR: Teremenko, V. N. (Kiev); Nizhenko, V. I. (Kiev); Sklyarenko, L. I. (Kiev) ORG: none TITLE: Surface tension and density of molten alloys of the system Ni-Ga and their miscibility with Al sub 2 0 sub 3 SOURCE: AN SSSR. Izvestiya. Metally, no. 2, 1966, 188-192 TOPIC TAGS: surface tension, molten metal, nickel alloy, gallium alloy, aluminum oxide, alloy phase diagram, metal property, specific density, specific volume (6) ABSTRACT: This report shows that on the isotherm of free surface energy (6) of molten alloys of the system <u>Ni-Al</u> there is a clearly pronounced (6) of inflection corresponding in composition to the congruently melt- point of inflection corresponding in composition to the congruently melt- ing intermetallide NiAL Gallium Ms an analog of aluminum and therefore ing interest to study the surface properties of the Ni-Ga system and to compare them with the phase diagram.	
The temperature and concentration of the solid states differ alloys in the Ni-Ga system were determined. It was established that specific volumes of alloys both in the molten and in the solid states differ sharply from additive values. The temperature and concentration relationships of the free surface The temperature and concentration were studied. energy of molten alloys in the Ni-Ga system were studied. It was shown that the isotherm plotted from experimental data passes	
UDC: 669.017.12 0901	

C NR: AR7000858	SOURCE CODE: UR/0058/66/000/009/E011/E011
UTHOR: Yeremenko,	V. N.; Nizhenko, V. N.; Sklyarenko, L. I.
TITLE: Temperature of	dependence of the free surface energy of molten iron
OURCE: Ref. zh. Fiz	ika, Abs. 9E92
EF SOURCE: Sb. Pov ikh tverd. fazəkh, Nal	verkhnostn, yavleniya v rasplavakh i voznikayushchikh i "chik, 1965, 287-292
OPIC TAGS: tempera urface energy, surface	ture dependence, molten metal, carbonyl iron, free e energy
as carbonyl iron, anne m Hg vacuum. Consider Apression haracteristics of the m	ce tension ( $\sigma$ ) of molten iron in the 1540-1750C temper by the lying-drop method. The object of the investigat ealed in hydrogen at 1000-1200C and remelted in a 10 <sup>-</sup> deration of all possible measurement errors leads to the $r=1856\pm2.3-0.23\pm0.02$ ( $t=1534$ ). The thermodynamic nolten iron surface are computed from the data of $\sigma$ and $r_{1}$ [Translation of abstract] [NT]

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IJTHOR:	Nizhenskiy, A.	D.; Khrizman,	5. 5.		BFI
RG: In	stitute of Elect	trodynamics, A	N UkrSSR (Institu	t elektrodinamiki A	N UKrSSR)
TITLE: diode	Design of a temp	perature stabi	lized reference v	oltage source using	; a Zener
SOURCE: (Convers 1965, 15	ion and stabili:	obrazovaniye i zation of elec	. stabilizatsiya e tromagnetic proce	lektromagnitnykh pr sses). Kiev, Naukov	otsessov a dumka,
	\GS: voltage sta reference	abilizer, Zene	er diode, temperat	ure stabilization,	thermistor,
is given proves i The refe ing tran emitter	h. The addition its performance a erence voltage i maistor Ql is dr follower is hig diada is such n	of a compensa as a voltage s s developed ac iven by the re h and the outp educed, as is	ting circuit to a stabilizing elemen cross the Zener di ference voltage. but impedance is l the effect of the	ized voltage refere Zener diode consid t. Figure 1 shows ode D. The emitter The input impedance ow; thus the loadin external load acro eference diode can	the circuit. follower us- ce of the ng on the re- oss the out-
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WTHOR: Mithemskiy, A. D.; Khrizman, S. S. (Candidate of technical sciences) RG: none ITLE: High-accuracy scalconductor stabilizer OURCE: Mekhanizatsiya i avtomatizatsiya upravleniya, no. 2, 1966, 28-30 PLALANCH, current stabilizer, current stabilizer, current stabilization BSTRACT: The development (at the nstitute of Electrodynamics, AN UkrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) ide is reported. The distinguishing eatures of the circuit used (see figure) re: (1) A high-input-resistance emitter ollower is employed as a load of the emerature compensation of the reference oltage in the output circuit of the		
WTHOR: Mishenskiy, A. D.; Khrizman, S. S. (Gandidate of technical sciences) RG: none TTLE: High-accuracy scalconductor stabilizer OURCE: Mekhanizatsiya i avtomatizatsiya upravleniya, no. 2, 1966, 28-30 PLLLANCH OPIC TAGS: semiconductor stabilizer, current stabilizer, current stabilization BSTRACT: The developement (at the nstitute of Electrodynamics, AN UKrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) ide is reported. The distinguishing eatures of the circuit used (see figure) re: (1) A high-input-resistance emitter ollower is employed as a load of the emerature compensation of the reference oltage in the output circuit of the matter follower is used; the compensation	ACC NR: AP7004255 (A) SOURCE	E CODE: UR/0432/66/000/002/0028/0030
TTLE: High-accuracy scalconductor stabilizer OURCE: Mekhanizatsiya i avtomatizatsiya upravleniya, no. 2, 1966, 28-30 PLALACH, OPIC TARS: semiconductor stabilizer, current stabilizer, current stabilization ESTRACT: The development (at the nstitute of Electrodynamics, AN UKrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) ide is reported. The distinguishing eatures of the circuit used (see figure) re: (1) A high-input-resistance emitter ollower is employed as a load of the emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation		
OURCE: Mekhanizatsiya i avtomatizatsiya upravleniya, no. 2, 1966, 28-30 PELLACH, current stabilizer, current stabilization BSTRACT: The developement (at the nstitute of Electrodynamics, AN UkrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) iode is reported. The distinguishing eatures of the circuit used (see figure) re: (1) A high-input-resistance emitter ollower is employed as a load of the ener diode; this enhances the stabiliza- ion factor of the circuit; (2) A emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation	ORG: none	
OPIC TAGS: semiconductor stabilizer, current stabilizer, current stabilization ESTRACT: The developement (at the institute of Electrodynamics, AN UkrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) ide is reported. The distinguishing eatures of the circuit used (see figure) a re: (1) A high-input-resistance emitter ollower is employed as a load of the ener dide; this enhances the stabiliza- ion factor of the circuit; (2) A emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation	TITLE: High-accuracy sociconductor stabilizer	
OPIC TAGS: semiconductor stabilizer, current stabilizer, current stabilization ESTRACT: The developement (at the institute of Electrodynamics, AN UkrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) ide is reported. The distinguishing eatures of the circuit used (see figure) a re: (1) A high-input-resistance emitter ollower is employed as a load of the ener dide; this enhances the stabiliza- ion factor of the circuit; (2) A emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation	SOURCE: Mekhanizatsiya i avtomatizatsiya upravle	iniya, no. 2, 1966, 28-30
institute of Electrodynamics, AN UkrSSR) f a high-accuracy current stabilizer ased on a voltage-regulating Si (Zener) iode is reported. The distinguishing eatures of the circuit used (see figure) re: (1) A high-input-resistance emitter ollower is employed as a load of the ener diode; this enhances the stabiliza- ion factor of the circuit; (2) A emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation	to las a mel	
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ener diode; this enhances the stabiliza- ion factor of the circuit; (2) A emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation	ue: (I) A high-input-resistance emitter falls	
ion factor of the circuit; (2) A emperature compensation of the reference oltage in the output circuit of the mitter follower is used; the compensation	ener diode; this enhances the stabiliza-	× × 10 10 [13] m, 2 = 3 m, 6,100 [15] = D
oltage in the output circuit of the mitter follower is used; the compensation	ion factor of the circuit; (2) A	
mitter follower is used; the compensation	emperature compensation of the reference	San 1996 and an
ard 1/2 UDC: 621.316.722.1:621.382	mitter follower is used; the compensation	a
	Card 1/2	WDC: 621.316.722.1:621.382

CIA-RDP86-00513R001137 "APPROVED FOR RELEASE: Tuesday, August 01, 2000 ACC NR: AP7004255 circuit is designed from temperature characteristics of the Zener diode and the emitter follower. In the figure: 1 - controlling transistor, 2 and 3 - two-stage transistorized amplifier, 4 - emitter follower, D - voltage-regulating D808 Si diode. Voltage variation of 0.02 is caused by a temperature variation Experimental data: of 10--50C; stabilizer error of 0.1% is caused by a supply-voltage variation of ± 20%; a load variation of 0.1--150 ohme causes a stabilizer error of 0.07%; after a continuous 10-hr operation, the stabilized current differed by ± 0.04% from the current obtained after a 15-min operation. The above stabiliser has been in operation since 1963 in an automatic differential calorimeter outfit. Orig. art. has: 1 figure and 1 formula. SUB CODE: 09 / SUBM DATE: none / ORIG REF: 003 Card 2/2

C NR: AR7000956 SOURCE CODE: UR/0275/66/000/011/V025/V025
AUTHOR: Nizhenskiy, A. S.; Khrizman, S. S.
TITLE: High-precision semiconductor current regulator
SOURCE: Ref. zh. Elektronika i yeye primeneniye, Abs. 11V165
REF SOURCE: Mekhaniz. i avtomatiz. upr. Nauchno-proizv. sb., no. 2, 1966, 28-30
TOPIC TAGS: current regulator, transistor, cascade amplifier, voltage regulato
ABSTRACT: A current regulator, developed at the Institute of Electrodynamics, AN Ukrainian SSR, was assembled using a circuit with a regulating transistor, a twin-cascade d-c amplifier, and a reference-voltage source with a silicon stabilitron tube connected in series to the base circuit of the output-emitter repeater. A variable standard resistance and a load resistance are connected to the emitter circuit of the regulating transistor temperature compensation, according to the condition cited, is accomplished with the aid of a network consisting of a linear resistance and a thermoresistor connected in parallel to the reference
UDC: 621. 316. 722. 1

ACC NR:	AR7000956
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voltage divider. For insuring temperature stability, a reference stabilitron tube, the emitter repeater transistor, and the thermoresistor are placed in a heavy thermostat of red copper. With a temperature change from +10 to +50°C, the reference voltage showed a change of about 0.02%, With a change in line voltage of  $\pm$  20, the load resistance changed within the limits of 0.1-150 ohms and the output current showed a change of < 0.04%. The voltage regulator has operated in a differential-calorimeter circuit since 1963. With an uninterrupted operation of 6-8 hr per day, the current instability has not exceeded  $\pm 4.1\%$ . The bibliography contains 3 titles. [Translation of abstract] [NT] SUB CODE: 09, 20/ Card 2/2

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CIA-RDP86-00513R0011373



NIZHIBITSKIY, O.N.

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Investigating the causes of the breaking off of the pendulum bobbin holder from the friction cylinder on machines processing synthetic fibers. Izv.vys.ucheb.zav.; tekh.tekst.prom. no.5:123-129 <sup>6</sup>4. (MIRA 18:<sup>1</sup>) 1. Leningradskiy institut tekstil<sup>1</sup>noy i legkoy promyshlennosti imeni S.M.Kirova.

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NIZHIBITSKIY, O.N.

Manahar Asian

Vibration and self-centering of the elastic support of pendulum bobbin holders. Izv. vys. ucheb. zav.; tekh. teks. prom. no.6: 118-123 165. (MIRA 19:1)

1. Leningradskiy institut tekstil'noy i legkoy promyshlennosti imeni S.M. Kirova. Submitted May 11, 1965.

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### NIZHIVENKO, L.N., aspirant

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Copper content of the teeth under normal conditions and in alveolar (HIRA 14:5) pyorrhea. Stomatologiia 40 no.1:32-35 Ja-F '61.

1. Iz kafedry terapevticheskoy stomatologii (zav. - prof. Ye.Ye. Platonov) i kafedry obshchey khimii (zav. - dotsent A.A.Zats) Moskovskogo meditsinskogo stomatologicheskogo instituta (direktor dotsent G.N.Beletskiy). (COPPER IN THE BODY) (GUNS-DISEASES)



G  4

NIZHNEV, Ye.P. Raise the quality requirements for crossing installations under roads. Stroi. truboprov. 8 no.12:29 D '63. (MIRA 17:4) 1. Stroitel'noye upravleniye No.14 tresta Mosgazprovodstroy, Podol'sk.

MATSELINSKIY, R.N., kand. tekhn. nauk; TURKATENKO, O.D., inzh; WIZHNICHENKO, I.K., insh. Making large precast reinforced concrete slabs in construction yards. Biul. stroi. tekh. 12 no.4:1-4 Ap '55. (MIRA 11:12) 1.TSentral'nyy nauchno-issledovatel'skiy institut promyshlemnykh soorusheniy. (Concrete slabs)

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BERDICHEVSKIY, G.I., kand.tekhn.nauk; DMITRIYEV, S.A., kand.tekhn.nauk;
MIKHAYLOV, K.V., kand.tekhn.nauk; GVOZDEV, A.A., prof., doktor tekhn.nauk; MIKHAYLOV, V.V., prof., doktor tekhn.nauk; BULGATOV, V.S., kand.tekhn.nauk; VASIL'YEV, A.P., kand.tekhn.nauk; SVETOV, A.A., kand.tekhn.nauk; FRENKEL', I.W., kand.tekhn.nauk; SVETOV, A.A., kand.tekhn.nauk; FRENKEL', I.W., kand.tekhn.nauk; SVETOV, A.A., kand.tekhn.nauk; FRENKEL', I.W., kand.tekhn.nauk; BELOBROV, I.K., inzh.; MATKOV, N.G., inzh.; HITNIK, G.S., inzh.; SKLYAR, B.L., inzh.; SHILOV, Ye.V., hzh.; HASENKO, I.D., inzh.; NIZHNICHENKO, I.P., inzh.; FILIPFOVA, G.P., inzh.; HIZERNYUK, B.N., kand.tekhn.nauk; SHETNFEL'D, N.K., kand.tekhn.nauk; BALAT'YEV, P.K., kand.tekhn.nauk; SHEBARASH, I.P., kand.tekhn.nauk; HITGARTS, L.B., kand.tekhn.nauk; SHIFRIN, M.A., kand.tekhn.nauk; FETROVA, V.V., red.izd-va; TEKEINA, Te.L., tekhn.red.

[Temporary instruction on the technology of making prestressed reinforced concrete construction elements] Vremennais instruktsiis po tekhnologii izgotovleniis predvaritel'no napriazhennykh zhelezobetonnykh konstruktsii. Moskva, Gos.izd-vo lit-ry po stroit., arkhit. i stroit.materialem, 1959. 255 p. (MIRA 12:12) (Continued on next card)

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CIA-RDP86-00513R0011373
BERDICHEVSKIY, G.I .--- (continued) Card 2.

بوجواه الرجيسومين بالسالية الأرا

1. Akademiya stroitel'stva i arkhitektury SSSR. Institut betona i zhelezobetona, Perovo. 2. Nauchno-issledovatel'skiy institut betona i zhelezobetona Akademii stroitel'stva i arkhitektury SSSR (for Gvozdev, V.V.Mikhaylov, Berdichevskiy, Bulgakov, Vasil'yov, Dmitriyev, Yavgen'yev, K.V.Mikhaylov, Mulin, Svetov, Frenkel', Belobrov, Matkov, Mitnik, Sklyar, Shilov). 3. Nauchno-issledovatel'skiy institut organizatsii, mekhanizatsii i tekhpomoshchi Akademii stroitel'stva i arkhitektury SSSR (for Mašenko, Nizhnichenko, Filippova, Mizernyuk, Sheynfel'd). 4. Nauchno-issledovatel'skiy institut Glavmosprometroymaterialov (for Balat'yev, Barbarash). 5. Nauchnoissledovatel'skiy institut po stroitel'stvu Minstroya RSFSR (for Mitgarts, Shifrin). 6. Deystvitel'nyye chleny Akademii stroitel'stva i arkhitektury SSSR (for Gvozdev, V.V.Mikhaylov). (Prestressed concrete)

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## MITTUREVA, T.T.; NIZHNIK, A.T.

Faster method for determining gallium in the by-products of zinc pro-duction. Ukr.khim.zhur. 24 no.6:790-793 '58. (MIRA 12:3) (Gallium--Analysis) (Polarography) (Ehodamine)

APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R0011373

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AUTHORS: TITLU:	On the Question of a Polarographic Method for the Determination of Indium (K voprosu o polyarograficheskom
	metode opredeleniya indiya)
PERIODICAL:	Zhurnal analiticheskoy khimii, 1959, Vol 14, Nr 1, pp 37-40 (USSR)
ADSTRACT:	Among the methods for the quantitative determination of indium. the polarographic method is now the most widely employed. This method calls for the complete separation of copper and cadmium as the half-wave potentials of these elements are very near to that of indium. For the determination of indium in industrial products containing one-hundredth percentages of indium or mor the authors suggest the amalgam method for the preparation of the solutions. The initial solution, which besides indium contains 20% of free sulfuric acid or an equivalent quantity o other sulfates, is worked up with zinc amalgam at normal temperature. All elements causing disturbance to the polarographic determination of indium are removed from the solution, while indium is maintained in the latter.
Card 1/3	

On the Question of a Polarographic Method for the Determination of Indium SOY/75-14-1-6/. ?

Sodium chloride or another coluble chloride (about 10% of weight of solution) is added to the purified solution, and indium is then polarographed. The addition of EnOl effects S. normal reduction of indium ions in sulfuric acid solutions, i... which the polarographic wave of indium does not take place without the chloride addition (Refs 13-16). The cause for the retarded reduction of indium ions in sulfuric heid colutions lies in the formation of complex amions of indium. This process is independent of the nature of the cation of the sulfates introduced (hydrogen or metal). The half-wave potential of indium in hydrochloric acid solution amounts to -0.597 V (with respect to a saturated calomel electrode), whereas it is -1.06 V in sulfuric acid solution, and that of cadmium in sulfuric acid solution is -0.642 V. The great difference in the potential values permits the complete separation of indium and cadmium in sulfuric acid solutions by the eid of zinc analgam. As, Sb, Bi, Cu, Tl, Se, Sn, Ti, Fe(III) and some other elements are reduced by zinc amalgam. Higher valency elements are reduced

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APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-

"APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137 sov/75-14-1-6/32 On the Question of a Polarographic Method for the Determination of Indium to lower ones. (Fe(III), V(V), Cr(VI), Ti(IV) ). The new method elaborated is accurately described. It was tested on several indium-containing raw materials. The results are described. There are 1 figure, 2 tables, and 20 references, 16 of which are Soviet. ASSOCIATION: Institut obshchey i neorganicheskoy khimii AN USBA, Miyev (Institute of General and Inorganic Chemistry of the AS UkrSSR, Kiyev) July 24, 1957 SUBMITTED: Card 3/3 





18.3100108721878 S/073/61/027/002/003/004 B101/B209NUTHORS:Mizhnik, A. T. and Bykova, M. I.AUTHORS:Electrochemical study of indium-bismuth amalgamTITLE:Electrochemical study of indium-bismuth amalgamTITLE:Ukrainskiy khimicheskiy zhurnal, v. 27, no. 2, 1961, 171-175DENIODICAL:Ukrainskiy khimicheskiy zhurnal, v. 27, no. 2, 1961, 171-175TEXT:The problem of the present paper is the extraction of indium from tailings of non-ferrous metallurgy in the form of amalgam in the present bismuth. For this purpose, the behavior of I n in the ternary system inead at 0.5 a/m <sup>2</sup> , 180C. The amalgam surface was 2.6 cm <sup>2</sup> ; platinum was used as cathode; the electrolyte consisted of 55 g/l inCl3 and 10 g/l RCL. metals was 1.4%. Fig. 2 shows the change of the potential and 10 g/n and ifferent in/Bi ratios in such a way that the total concentration of in metals was 1.4%. Fig. 2 shows the change of the potential as a function of orcesponding to the compounds In_Bi and InBi. An examination with pure indium amalgam and In-Bi amalgam with the same indium content confirmed the indium amalgam and In-Bi amalgam with the same indium content confirmed the indium amalgam and In-Bi amalgam with the potential of In-Bi emalgam as con- indium amalgam and In-Bi amalgam with the same indium content confirmed the indium amalgam and In-Bi amalgam with the potential of In-Bi emalgam as con- indium amalgam and In-Bi emalgam with the same indium content confirmed the indium amalgam and In-Bi emalgam with the potential of In-Bi emalgam as com- indium amalgam and In-Bi emalgam with the potential of In-Bi emalgam as com- indium amalgam and In-Bi emalgam with the potential of In-Bi emalgam as com- indium amalgam and In-Bi emalgam with the potential of In-Bi emalgam as com- indium amal			AMAN TESS R		Ĩ
18.3100AUTHORS:Hizhnik, A. T. and Bykova, M. I.TIYLE:Electrochemical study of indium-bismuth amalgamTIYLE:Ukrainskiy khimicheskiy zhurnal, V. 27, no. 2, 1961, 171-175PERIODICAL:Ukrainskiy khimicheskiy zhurnal, V. 27, no. 2, 1961, 171-175TEXT:The problem of the present paper is the extraction of indium fromtailings of non-ferrous metallurgy in the form of amalgam in the presence oftailings of non-ferrous metallurgy in the form of In-Bi-Hg amalgam was firstismuth.For this purpose, the behavior of In in the ternary systemin-Bi-Hg was studied.The equilibrium potential of In-Bi-Hg amalgam was prepared inmeasured at 0.5 a/m2, 18°C.The amalgam surface was 2.6 cm2; platinum wasused as cathode; the electrolyte consisted of 35 g/l InCl3 and 10 g/l HCl.The maximum sclubility of Bi in Hg being 1.49 wt%, amalgam was prepared inthe maximum sclubility of Bi in Such a way that the total concentration of the twodifferent In/Bi ratios in such a way that the total concentration of the twodifferent In/Bi ratios in such a way that stomic ratios of 2 : 1 and 1 : 1.	 •		a 1073/61	/027/002/003/004 08	
corresponding and In-Bi amaigue of the potential	AUTHORS: TITLE: PERIODICAL: TEXT: The p tailings of bismuth. Fo In-Bi-Hg was measured at used as cat The maximum different I	Hizhnik, A. T. and Bykov Electrochemical study o Ukrainskiy khimicheskiy problem of the present pa non-ferrous metallurgy i for this purpose, the beha to this purpose, the beha studied. The equilibri to 5 a/m <sup>2</sup> , 18°C. The amount thode; the electrolyte com m sclubility of Bi in Hs In/Bi ratios in such a wa	va, M. I. f indium-bismuth a y zhurnal, v. 27, r per is the extract n the form of amal vior of In in the um potential of Ir algam surface was nsisted of 35 g/l being 1.49 wt%, am y that the total of change of the pote	malgam no. 2, 1961, 171-175 ion of indium from gam in the presence of ternary system n-Bi-Hg amalgam was firs 2.6 cm <sup>2</sup> ; platinum was InCl3 and 10 g/l HCL. algam was prepared in concentration of the two ential as a function of ios of 2 : 1 and 1 : 1, remination with pure	0 is
result. As the marimum dot Card 1/6	result.	As the maximum do			

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Electrochemical study .....

pared to pure In amalgam was 0.022 v, it was assumed that the interaction between In and Bi in Hg would not considerably influence the electrodeposition of indium. This was studied experimentally with amalgam having a ratio of 47 : 53, corresponding to In<sub>2</sub>Bi, and 65 : 35, corresponding to InBi. A 15x4 mm platinum plate served as a cathode. The current density was 0.04 a/cm<sup>2</sup>, and the terminal voltage 4 v. Amalgam and electrolyte (10 g/l InCl3, 73 g/l HCl) were stirred with 250-300 rpm. Fig. 5 shows the change of the anode potential. It could be seen from this and from the analysis (determination of In in amalgam and electrolyte polarographically, and of Bi by spectrum analysis) that about 99% In may be obtained from an In-Bi amalgam. Electrolysis was finished as soon as the thiourea added to the electrolyte indicated the dissolution of Bi in the electrolyte by a yellow ccloring. The electrodeposited indium was investigated by spectrum analysis. It contained 0.018-0.020 wt% of Bi. Fig. 4 illustrates the effect of Bi on the limiting of a 1% In amalgam. The reduction of the limiting current in the presence of Bi may be explained by impeded diffusion of the indium atoms in In-Bi-Hg. There are 5 figures, 1 table, and 9 references: 6 Soviet-bloc and 3 non-Soviet-bloc. The 2 references to English-language publications read as follows: Ludwick Maria Thompson, Indium, New York,

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"APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137 22434 S/080/61/054/007/009/016 1043, 1087, 1208 D223/D305 54700 Nizhnik, A.T., and Bykova, M.I. AUTHORS: Electrochemical investigation of the system of TITLE: gallium-zinc-mercury PERIODICAL: Zhurnal prikladnoy khimii, v. 34, no. 7, 1961, 1554 - 1561 TEXT: Metallic gallium obtained from residues during Pb and Zn production always contain the latter as an impurity. The difference in the potential of zinc (-0.76 v) and gallium (-0.52 v) suggest the possibility of electrolytic separation of the two metals. The present work deals with the possibility of electrolytically separating zinc and gallium and also with the optimum conditions under which this separation can take place. To carry out the investigation metallic Ga, Zn and Hg were used of following purities: Ga = 99.99 % with trace impurities of Al, Zn, Pt and Cu: Zn - 99.999 %; mercury was purified by method employed in polarography (polaro-Card 1/7

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 $\begin{array}{c} 22h3h\\ S/080/61/034/007/009/016\\ D223/D305\\ \end{array}$ graphic analysis). The polarization curves were obtained by the usual compensating method, the measurements taken on the potentiometer system M-1. The proportional volume ratio of amalgam and solution was 1:10. All measurements were done at room temperature ( $\sim 20^{\circ}$ C). The gallium estimation was done colorimetrically. The data obtained on current density and its effect on the cathodic and anodic potential of zinc and gallium amalgam in 1 N H2SO4 is

and anodic potential of zinc and gallium amazgam in 1 x my be seen given in Fig. 1 of 1N HCl in Fig. 2. From this data it may be seen that the polarization curves of zinc and gallium amalgam in H2SO4 and HCl solutions are similar. Zn is seen to be more positive than gallium on the cathodic side and the cathodic potential of Zn/Hg at current density of 100 mA/cm<sup>2</sup> is equal to -1.5 v while Ga/Hg potential was -1.6 v (in respect of N.K.C.). Similar relations hold for the anodic process where for the same current density, the zinc potential was 0.74 v and gallium -0.47 v (in respect of N.K.C.). Here zinc is seen to be more electronegative than gallium. These relations suggested the possibility of electrolytical separation of two metals. The author then briefly describe their in-

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22434 s/080/61/034/007/009/016 D223/D305

·Electrochemical investigation ...

vestigation on stability of Zn and Ga amalgams in respect of H2SO4. The results show that the gallium amalgam is more stable than zinc. After 3 hours the transfer of gallium into 2N H<sub>2</sub>SO<sub>4</sub> solution is 0.5 % hence the small solubility of Ga amalgam in H<sub>2</sub>SO<sub>4</sub> explains the absence of gallium on the Hg cathode. Composite polarization curves, of Zn and H2 and Ga and H2 were recorded as well as the individual curves. This is done by association of part of the total current with the deposit of one of the elements under investigation, and the current density is worked out from the material balance of cathode and the composition of products. This approach is adopted when there are several elements present and current is associated with each one. As long as experiments for the potential determination and electrode balance are carried out under same conditions, the above approach is valid. The electrolyte used was a 1N. H2SO4 solution containing 3.33 g/l of Zn and 2.33 g/l of Ga. The results indicate that the maximum quantity of gallium on ca-thode was 0.4 wt. %. From the individual polarization curves of zinc and gallium, it was shown that Zn emerges at potential - 1.1v

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APPROVED FOR RELEASE: Tuesday, August 01, 2000



"APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137 22434 5 5/080/61/034/007/009/016 Electrochemical investigation ... D223/D305 amalgam contained only 157/57 mls of Ga. There are 6 figures, 3 tables and 12 references: 8 Soviet-bloc and 4 non-Soviet-bloc. The ÷1 references to the English-language publications read as follows: L. Dennis, A. Bridgeman, J.Am. Chem. Soc., 40, 15, 31, 1918; T. Richards, A. Bojer, J. Am. Chem. Soc., 43, 275, 1921; W.M. Latimer, The oxidation States of the Elements and their Potentials in Aqueous Solutions, N.Y., 1938. 5 SUBMITTED: July 4, 1960 Fig. 1. Effect of current density on anodic and cathodic potentials of Zn and Ga amalgams in 1N solution of H2SO4. Legend: A - current density (mA/cm<sup>2</sup>); B - potential (v); 1,2,3 anodic curves corresponding to 1,2,3 gr. atoms met/1 of Hg 4,5,6 cathodic curves corresponding to 1,2,3 gr. atom/1 Hg. I - gallium, II - zinc. Card 5/7

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Nizhnik, A. T. AUTHOR:

Amalgam method for the recovery of rare dispersed metals TITLE:

Doklady Akademii nauk SSSR, v. 137, no. 2, 1961, 366-368 PERIODICAL:

TEXT: The author suggests an amalgam method of extracting and refining highpurity indium and gallium to eliminate difficulties in conventional methods. The extraction of thallium was discussed by M. T. Kozlovskiy et al. (Ref 11: Tavetnyye Metally, 1, 30, 1958), and A. A. Shokol, L. F. Kozin (Ref. 12: Ukr. khim. zhurn., 25, no. 2, 249, 1959. The principles of the author's method are such: a) considerable solubility of these metals in mercury (In  $\approx$ 75, T1 45, Ga~2%; b) stability of their amalgams in aqueous solutions; c) no chemical interaction between these metals and mercury; d) overvoltage of hydrogen in analgams, whereby reactions in sufficiently acid solutions become possible; e) intensive diffusion in amalgams allowing the application of considerable current densities; f) strictly observed order of transition from the metals of solutions into amalgam, and vice versa; g) homogeneous

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THE REAL PROPERTY AND ADDRESS AND ADDRES AND ADDRESS AND A ADDRESS AND ADDRESS 20741 s/020/61/137/002/015/020 B103/B215 Amalgam method for the ... (ideally smooth) amalgam surface, and small interface separating the solution, thus eliminating side reactions (absorption, passivation, formation of galvanic elements, etc) and guaranteeing stable potential of the system; h) Sec. high specific gravity of mercury and amalgams, which may lead to the accumulation of considerable quantities of metal in a small volume of amalgam (~10 kg In in 11 of Hg). The production of In and Ga is based upon their transfer from Ģ solutions into amalgams by cementing on amalgams of metals which are more strongly electronegative than rare metals, e.g., Tl on Zn|Hg or Cd|Hg; In on Zn |Hg and Ga on Na |Hg. The metals are extracted from the developed amalgams by electrolytic (anodic) dissolution, the rare metal is simultaneously deposited on the cathode. Fig. 1 shows the sulfide separation of indium from heavy metals. Bi, Cu Sb, As, et al. are first deposited; by ZnS additions, after that In is bound. The extraction of indium by ZniHg, and of gallium by NaiHg are illustrated in Figs. 2 and 3 (T.T.Mityureva, I.S.Chaus and Z.V.Shekhter assited). Cd is cemented together with In, as their potentials are so close to each other  $(\pi_{1/2} \text{ In} = -0.58, \pi_{1/2} \text{ Cd} = -0.60 \text{ v})$ . In and Cd, however, can be quentita-Card 2/8

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Amalgam method for the ...

tively separated from sulfates containing an excess of sulfate ions. The indium potential is shifted by the formation of an indium complex anion  $(In(SO_4)_2)^-$ . Te. V. Zvagol'skaya proved that hydrochloric media are most suitable for the selective transfer of indium from amalgam. 90% of spectroscopically pure indium is obtained on the cathode at a current density between 0.05 and 0.1  $a/\pi^2$ . Further experiments of the author showed that under an electrolyte layer mercury starts evaporating from indium amalgam after 5 hr at 50°C so that mercury impurities in indium are eliminated. Table 3 gives the purity of indium refined by this method, and other types of indium. The purity was tested by B. I. Verkin and B. N. Aleksandrov by physical methods. Hence, the author concludes that the indium he refined is one of the purest types. There are 3 figures, 3 tables, and 19 references: 12 Soviet-bloc and 7 non-Soviet-bloc. The reference to the English-language publication reads as follows: Ref. 18: H. Meissner, R. Zdanis, Phys. Rev., 109, no. 3, 681 (1958). . . Card 3/8

TELESCOLOGICAL STRATES IN A STRATES AND A

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"APPROVED FOR RELEASE: Tuesday, August 01, 2000 CIA-RDP86-00513R001137 1 · • • • • 20741 s/020/61/137/002/015/020 B103/B215 Amalgam method for the ... Institut obshchey i neorganicheskoy khimii Akademii nauk ASSOCIATION: USSR (Institute of General and Inorganic Chemistry of the Academy of Sciences UkrSSR) November 3, 1960 by A. N. Frumkin, Academician PRESENTED: October 13, 1960 SUBMITTED: . Card 4/8 1

S/081/62/000/011/015/057 E111/E152

Nizhnik, A.T., and Chaus, I.S. **AUTHORS**: Method for the polarographic determination of indium TITLE: PERIODICAL: Referativnyy zhurnal, Khimiya, no.11, 1962, 140, abstract 11 D 85. (In the Symposium: 'Khim. fiz.-khim. i spektr. metody issled. rud. redk. i rasscyan. elementov' ('Methods of chemical, physico-chemical and spectral investigation of rare and dispersed ore elements'), M. Gosgeoltekhizdat, 1961, 92-95) A simplified method is described for the determination of small quantities of In in industrial products and wastes. This is based on preliminary separation of the interfering elements (As, Sb, Bi, Cu, Tl, Se, Te, Mo, Ti(4+), Fe3+, Cd, Cr(6+), V(5+), by reduction with Zn amalgam in a sulphuric-acid medium and subsequent polarography of In in the purified solution. 1-3 g of sample are decomposed by heating with a mixture of HNO3 and  $H_2S04$ , the liquid is evaporated till evolution of  $H_2S04$  fumes, Card 1/2

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1. 🗩 s/080/62/035/002/007/022 D235/D302 Nizbnik, A. T. and Shekhter, Z. V. AUTHORS: Study of the effect of certain impurities on the cementation of gallium with sodium amalgam TITLE: Zhurnal prikladnoy khimii, v. 35, no. 2, 1962, 295-300 PERIODICAL: TEXT: Dependence of the rate of separation of Ga into the amalgam on the temperature, rate of stirring and on alkali concentration was first studied. The degree of cementation increased with an increase in the speed of stirring and with rising temperature; the crease in the speed of stirring and with fight temperature, the optimum conditions were a temperature of  $50^{\circ}$ C, a speed of stirring of 400 rpm and an alkeli concentration of 50 g/l. In order to invest of 400 rpm and an alkeli concentration of 50 g/l. stigate the effect of impurities small amounts of Zn, Al, As, Sb and Mo were added to a solution containing 50 g NaOH and 0.4 g Ga per liter. Under the optimum conditions 10 ml of 1% Na amalgam were added to 50 ml of solution and cementation was allowed to proceed for 90 minutes, Al and As5+ were not reduced by sodium amalgam; zinc, like Ga, was reduced by the amalgam to the metal and easily Card 1/2

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S/080/62/035/002/007/022 D235/D302 Study of the effect ... dissolved in the mercury. As $^{3+}$  and Sb $^{3+}$  were reduced to the element, but did not dissolve in mercury and in the case of As, AsH, was evolved. Mo and V were energetically reduced to the lower valency state. The consumption of sodium amalgam during the cementation of gallium in the presence of the studied additions increases in the series  $Zn \langle Sb^{3+} \langle Mo^{4+} \langle As^{3+} \langle V^{5+} \rangle$ . The presence of such elements does not effect the degree of Ga cementation and only in the presence of V does the rate of cementation decrease by 10 - 20%. The reduction of V to a lower valency state is accompanied by a sharp increase in the breakdown of the sodium amalgam, but the authors established that cementation of gallium is possible even in the presence of large quantities of vanadium provided there is an excess of the amalgam. There are 2 figures, 2 tables and 16 references: 8 Soviet-bloc and 8 non-Soviet-bloc. The references to the Englishlanguage publications read as follows: P. de la Breteque, C. R., 243, 14, 958, (1956); R. MacMullen, Chem. Eng. Progr., 46, 9, 20, (1950); A. Angel and T. Lunden, Electroch. Soc., 99, 11, 435 (1952). SUBMITTED: October 24, 1960 Card 2/2Toples and a family

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